NSN 5961-01-363-4673

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-363-4673 **Inclosure Material:** Glass **Overall Length:** Between 0.150 inches and 0.170 inches **Overall Diameter:** 0.076 inches **End Application:** An/fps-108acd **Mounting Method:** Terminal **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 1.0 forward voltage, dc **Current Rating Per Characteristic:** 100.00 milliamperes forward current, average peak **Capacitance Rating In Picofarads:** 0.4 **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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